

FFSH2065BDN-F085

Silicon Carbide Schottky Diode, 650 V, 20 A

Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size & cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 49 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- AEC-Q101 Qualified
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

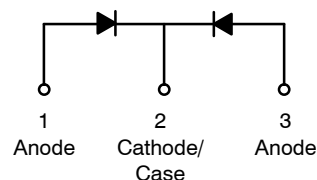
Applications

- Automotive HEV-EV Onboard Chargers
- Automotive HEV-EV DC-DC Converters

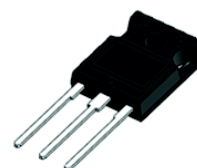


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Schottky Diode



TO-247-3LD
CASE 340CH

MARKING DIAGRAM



\$Y	= ON Semiconductor Logo
&Z	= Assembly Plant Code
&3	= Numeric Date Code
&K	= Lot Code
FFSH2065BDN	= Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFSH2065BDN-F085

ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit	
V_{RRM}	Peak Repetitive Reverse Voltage	650	V	
E_{AS}	Single Pulse Avalanche Energy (Note 1)	49*/49**	mJ	
I_F	Continuous Rectified Forward Current @ $T_C < 136^\circ\text{C}$	10*/20**	A	
$I_{F, Max}$	Non-Repetitive Peak Forward Surge Current	$T_C = 25^\circ\text{C}, 10 \mu\text{s}$	650	A
		$T_C = 150^\circ\text{C}, 10 \mu\text{s}$	570	A
$I_{F, SM}$	Non-Repetitive Forward Surge Current $T_C = 25^\circ\text{C}$	Half-Sine Pulse, $t_p = 8.3 \text{ ms}$	42	A
P_{tot}	Power Dissipation	$T_C = 25^\circ\text{C}$	65	W
		$T_C = 150^\circ\text{C}$	22	W
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to +175	$^\circ\text{C}$	
	TO247 Mounting Torque, M3 Screw	60	Ncm	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

* Per Leg, ** Per Device

1. E_{AS} of 49 mJ is based on starting $T_J = 25^\circ\text{C}$, $L = 0.5 \text{ mH}$, $I_{AS} = 14 \text{ A}$, $V = 50 \text{ V}$.

THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max	2.3*/1.2**	$^\circ\text{C}/\text{W}$

* Per Leg, ** Per Device

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted (per leg))

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
V_F	Forward Voltage	$I_F = 10 \text{ A}, T_C = 25^\circ\text{C}$	-	1.38	1.7	V
		$I_F = 10 \text{ A}, T_C = 125^\circ\text{C}$	-	1.6	2.0	
		$I_F = 10 \text{ A}, T_C = 175^\circ\text{C}$	-	1.72	2.4	
I_R	Reverse Current	$V_R = 650 \text{ V}, T_C = 25^\circ\text{C}$	-	0.5	40	μA
		$V_R = 650 \text{ V}, T_C = 125^\circ\text{C}$	-	1	80	
		$V_R = 650 \text{ V}, T_C = 175^\circ\text{C}$	-	2	160	
Q_C	Total Capacitive Charge	$V = 400 \text{ V}$	-	25	-	nC
C	Total Capacitance	$V_R = 1 \text{ V}, f = 100 \text{ kHz}$	-	421	-	pF
		$V_R = 300 \text{ V}, f = 100 \text{ kHz}$	-	40	-	
		$V_R = 600 \text{ V}, f = 100 \text{ kHz}$	-	34	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Marking	Package	Shipping
FFSH2065BDN-F085	FFSH2065BDN	TO-247-3LD (Pb-Free / Halogen Free)	30 Units / Tube

TYPICAL CHARACTERISTICS

($T_J = 25^\circ\text{C}$ unless otherwise noted (per leg))

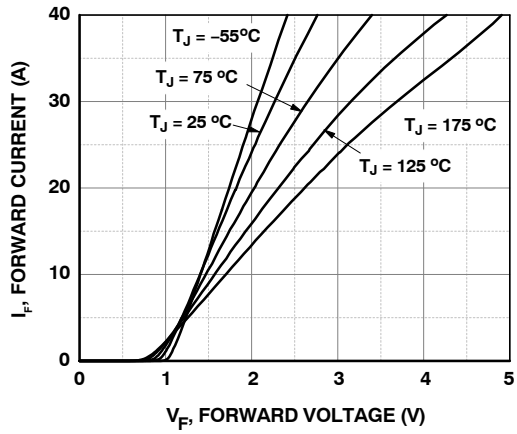


Figure 1. Forward Characteristics

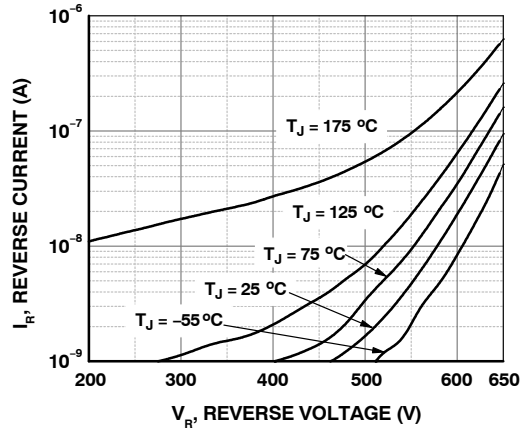


Figure 2. Reverse Characteristics

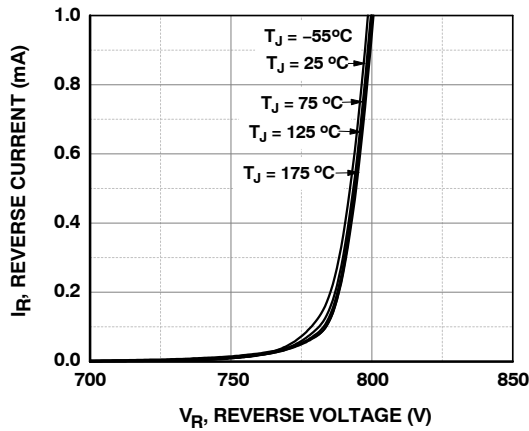


Figure 3. Reverse Characteristics

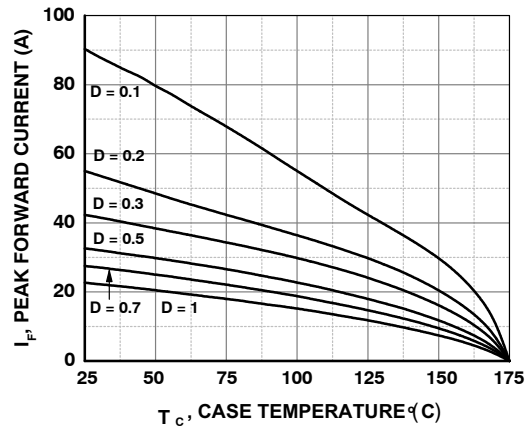


Figure 4. Current Derating

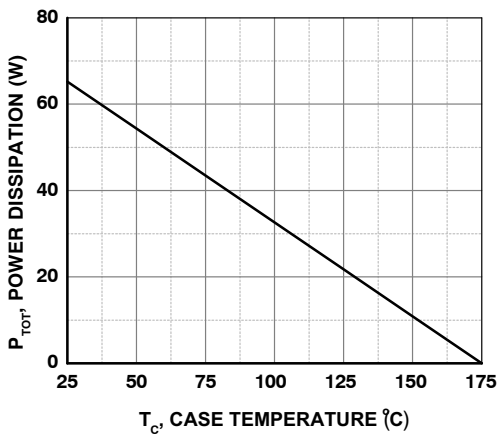


Figure 5. Power Derating

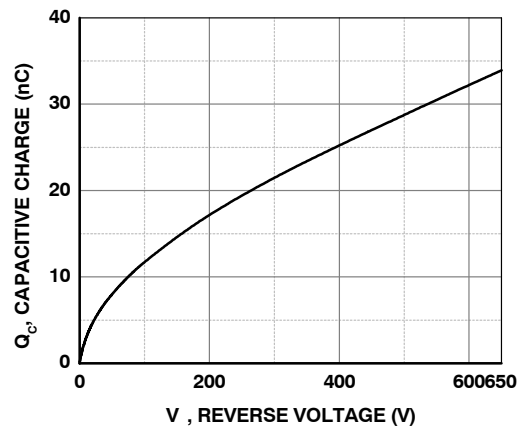


Figure 6. Capacitive Charge vs. Reverse Voltage

TYPICAL CHARACTERISTICS

($T_J = 25^\circ\text{C}$ unless otherwise noted)

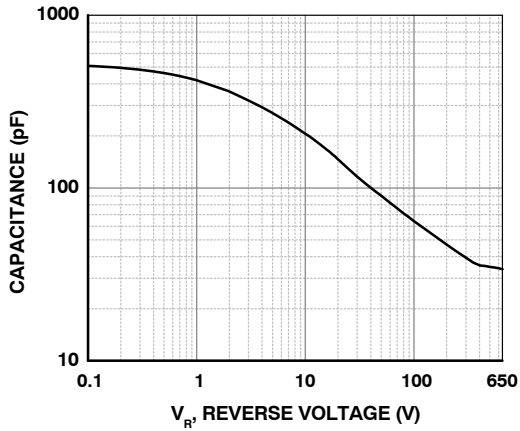


Figure 7. Capacitance vs. Reverse Voltage

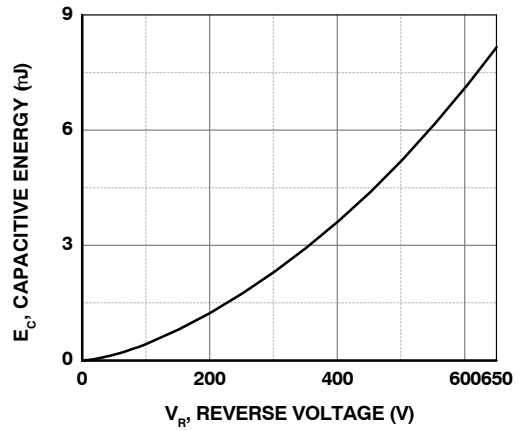


Figure 8. Capacitance Stored Energy

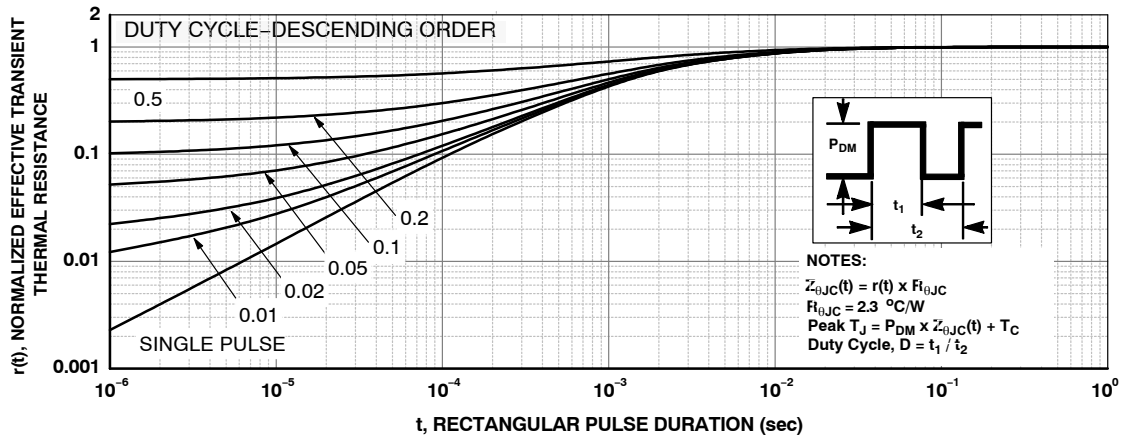


Figure 9. Junction-to-Case Transient Thermal Response Curve

TEST CIRCUIT AND WAVEFORMS

$L = 0.5 \text{ mH}$
 $R < 0.1 \ \Omega$
 $V_{DD} = 50 \text{ V}$
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)} / (V_{R(AVL)} - V_{DD})]$
 $Q1 = \text{IGBT (} BV_{CES} > \text{DUT } V_{R(AVL)} \text{)}$

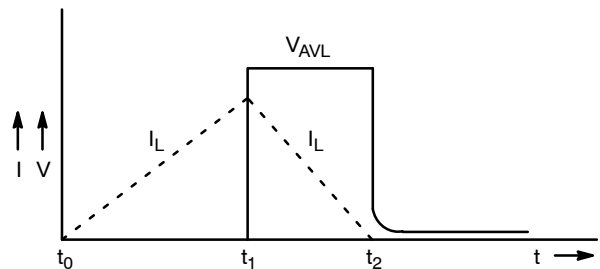
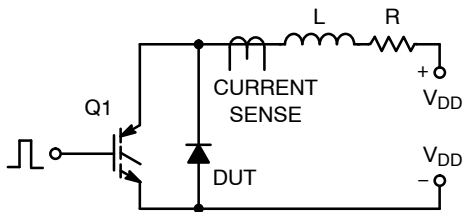


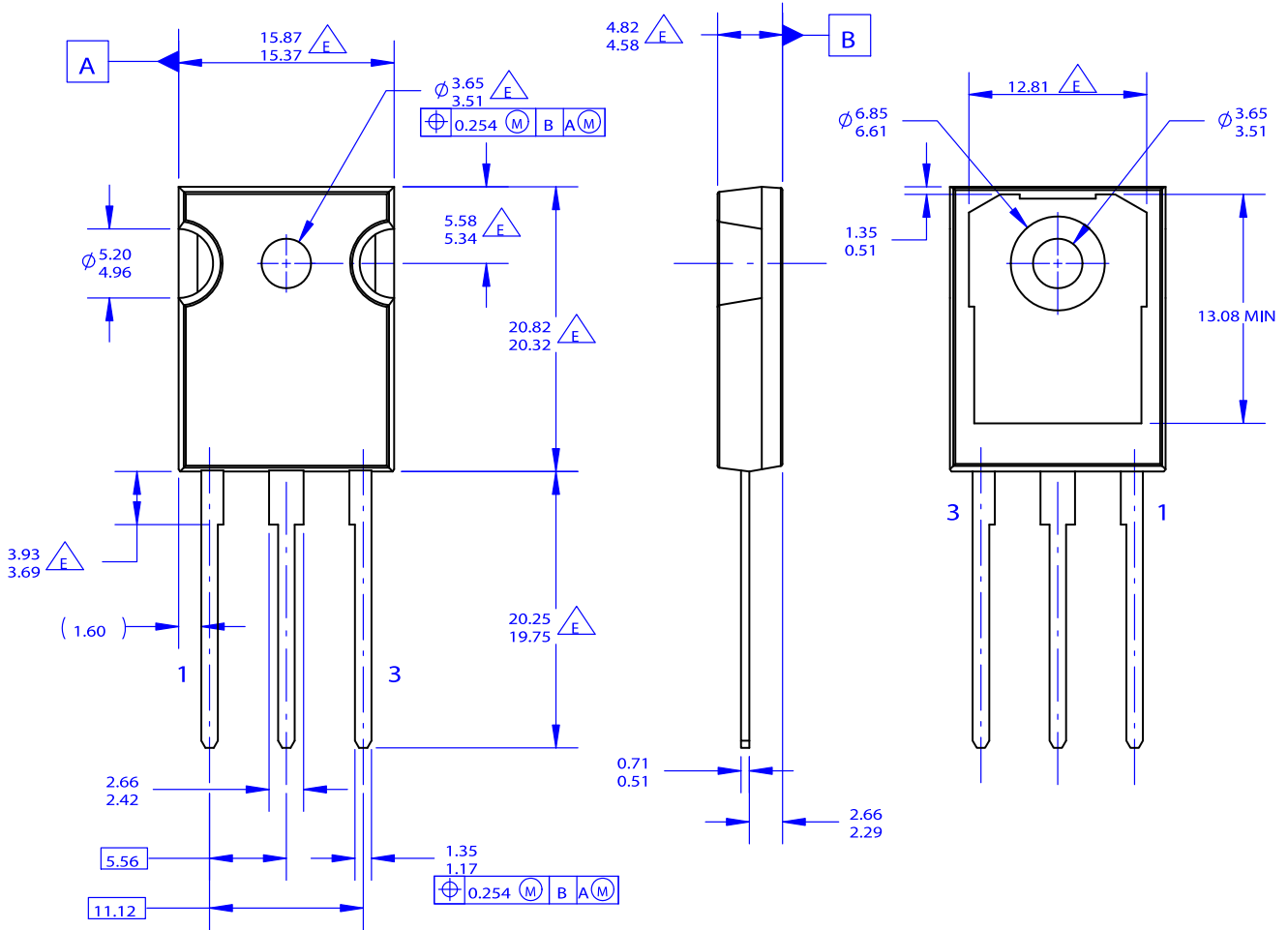
Figure 10. Unclamped Inductive Switching Test Circuit & Waveform

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

TO-247-3LD CASE 340CH ISSUE O

DATE 31 OCT 2016



NOTES: UNLESS OTHERWISE SPECIFIED.

- A. PACKAGE REFERENCE: JEDEC TO-247, ISSUE E, VARIATION AB, DATED JUNE, 2004.
- B. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- C. ALL DIMENSIONS ARE IN MILLIMETERS.
- D. DRAWING CONFORMS TO ASME Y14.5 - 1994

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